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# **Chip Monolithic Ceramic Capacitors**



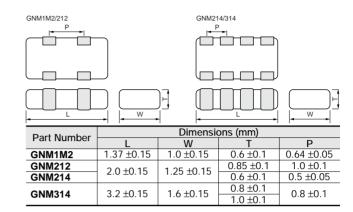
### **Capacitor Arrays**

#### ■ Features

- 1. High density mounting due to mounting space saving
- 2. Mounting cost saving

#### ■ Applications

General electronic equipment



#### **Temperature Compensating Type**

Part Number		GNM31			
LxW	3.2x1.6				
тс	C0G ( <b>5C</b> )				
Rated Volt.	100 ( <b>2A</b> )	50 ( <b>1H</b> )			
	part numbering code) and T (mm) Dimension (T Dir	nension part numbering code)			
10pF( <b>100</b> )	0.8(4)	0.8(4)			
11pF( <b>110</b> )	0.8(4)	0.8(4)			
12pF( <b>120</b> )	0.8 <b>(4</b> )	0.8(4)			
13pF( <b>130</b> )	0.8 <b>(4</b> )	0.8(4)			
15pF( <b>150</b> )	0.8 <b>(4</b> )	0.8(4)			
16pF( <b>160</b> )	0.8 <b>(4</b> )	0.8(4)			
18pF( <b>180</b> )	0.8(4)	0.8(4)			
20pF( <b>200</b> )	0.8(4)	0.8(4)			
22pF( <b>220</b> )	0.8(4)	0.8(4)			
24pF( <b>240</b> )	0.8(4)	0.8(4)			
27pF( <b>270</b> )	0.8(4)	0.8(4)			
30pF( <b>300</b> )	0.8(4)	0.8(4)			
33pF( <b>330</b> )	0.8(4)	0.8(4)			
36pF( <b>360</b> )	0.8(4)	0.8(4)			
39pF( <b>390</b> )	0.8(4)	0.8(4)			
43pF( <b>430</b> )	0.8(4)	0.8(4)			
47pF( <b>470</b> )	0.8(4)	0.8(4)			
51pF( <b>510</b> )	0.8(4)	0.8(4)			
56pF( <b>560</b> )	0.8(4)	0.8(4)			
62pF( <b>620</b> )	0.8(4)	0.8(4)			
68pF( <b>680</b> )	0.8(4)	0.8(4)			
75pF( <b>750</b> )	0.8(4)	0.8(4)			
82pF( <b>820</b> )	0.8(4)	0.8(4)			
91pF( <b>910</b> )	0.8(4)	0.8(4)			
100pF( <b>101</b> )	0.8(4)	0.8(4)			
110pF( <b>111</b> )	0.8(4)	0.8(4)			
120pF( <b>121</b> )	0.8(4)	0.8(4)			
130pF( <b>131</b> )	0.8(4)	0.8(4)			
150pF( <b>151</b> )	0.8(4)	0.8(4)			
160pF( <b>161</b> )		0.8(4)			
180pF( <b>181</b> )		0.8(4)			

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Part Number	GNM31					
LxW	3.2x1.6					
тс	C0G ( <b>5C</b> )					
Rated Volt.	100 ( <b>2A</b> )	50 ( <b>1H</b> )				
Capacitance (Ca	pacitance part numbering code) and T (mm) Dimension (T Dimen	sion part numbering code)				
200pF( <b>201</b> )		0.8(4)				
220pF( <b>221</b> )		0.8(4)				
240pF( <b>241</b> )		0.8(4)				
270pF( <b>271</b> )		0.8(4)				
300pF( <b>301</b> )		0.8(4)				
330pF( <b>331</b> )		0.8(4)				
360pF( <b>361</b> )		0.8(4)				

The part numbering code is shown in each ( ). The (4) code in T(mm) means number of elements (four). Dimensions are shown in mm and Rated Voltage in Vdc.

#### **High Dielectric Constant Type GNM1 Series**

Part Number	GNM1M					
LxW	1.37	x1.00				
тс	X7R ( <b>R7</b> )					
Rated Volt.	16 ( <b>1C</b> )	10 ( <b>1A</b> )				
Capacitance (Ca	pacitance part numbering code) and T (mm) Dimension (T Dimen	sion part numbering code)				
22000pF( <b>223</b> )	0.6(2)					
47000pF( <b>473</b> )	0.6(2)					
0.10μF( <b>104</b> )		0.6(2)				

The part numbering code is shown in each ( ). The (2) code in T(mm) means number of elements (two). Dimensions are shown in mm and Rated Voltage in Vdc.

### **High Dielectric Constant Type GNM2 Series**

Part Number	GNM21					
L x W	2.0x1.25					
тс	X7R ( <b>R7</b> )					
Rated Volt.	50 ( <b>1H</b> )					
Capacitance (Ca	Capacitance (Capacitance part numbering code) and T (mm) Dimension (T Dimension part numbering code)					
1000pF( <b>102</b> )	0.6(4)					
10000pF( <b>103</b> )	0.6(4)					

The part numbering code is shown in each ( ). The (4) code in T(mm) means number of elements (four). Dimensions are shown in mm and Rated Voltage in Vdc.

### **High Dielectric Constant Type GNM3 Series**

Part Number	GNM31							
LxW		3.2x1.6						
тс	X7R ( <b>R7</b> )					Y5V ( <b>F5</b> )		
Rated Volt.	100 ( <b>2A</b> )	50 ( <b>1H</b> )	25 ( <b>1E</b> )	16 ( <b>1C</b> )	100 ( <b>2A</b> )	50 ( <b>1H</b> )	16 ( <b>1C</b> )	
Capacitance (Ca	Capacitance (Capacitance part numbering code) and T (mm) Dimension (T Dimension part numbering code)							
220pF( <b>221</b> )	0.8(4)							

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Part Number				GNM31						
LxW	3.2x1.6									
тс		X7 ( <b>R</b>	7R 1 <b>7</b> )		Y5V ( <b>F5</b> )					
Rated Volt.	100 ( <b>2A</b> )	50 ( <b>1H</b> )	25 ( <b>1E</b> )	16 ( <b>1C</b> )	100 ( <b>2A</b> )	50 ( <b>1H</b> )	16 ( <b>1C</b> )			
Capacitance (Cap	acitance part nur	nbering code) and	T (mm) Dimension	(T Dimension part	numbering code)					
270pF( <b>271</b> )	0.8 <b>(4)</b>									
330pF( <b>331</b> )	0.8(4)									
390pF( <b>391</b> )	0.8(4)	0.8(4)								
470pF( <b>471</b> )	0.8(4)	0.8(4)								
560pF( <b>561</b> )	0.8(4)	0.8(4)								
680pF( <b>681</b> )	0.8(4)	0.8(4)								
820pF( <b>821</b> )	0.8(4)	0.8(4)								
1000pF( <b>102</b> )	0.8(4)	0.8(4)								
1200pF( <b>122</b> )	0.8(4)	0.8(4)								
1500pF( <b>152</b> )	0.8(4)	0.8(4)								
1800pF( <b>182</b> )	0.8(4)	0.8(4)								
2200pF( <b>222</b> )	0.8(4)	0.8(4)			0.8(4)					
2700pF( <b>272</b> )	0.8(4)	0.8(4)								
3300pF( <b>332</b> )	0.8(4)	0.8(4)			0.8(4)					
3900pF( <b>392</b> )	0.8(4)	0.8(4)								
4700pF( <b>472</b> )	0.8(4)	0.8(4)			0.8(4)					
5600pF( <b>562</b> )		0.8(4)								
6800pF( <b>682</b> )		0.8(4)								
8200pF( <b>822</b> )		0.8(4)								
10000pF( <b>103</b> )		0.8(4)								
12000pF( <b>123</b> )		0.8(4)								
15000pF( <b>153</b> )		0.8(4)								
18000pF( <b>183</b> )			0.8(4)							
22000pF( <b>223</b> )				0.8(4)		0.8(4)				
27000pF( <b>273</b> )				0.8(4)						
33000pF( <b>333</b> )				0.8(4)		0.8(4)				
39000pF( <b>393</b> )				0.8(4)						
47000pF( <b>473</b> )				1.0(4)		0.8(4)				
68000pF( <b>683</b> )				1.0(4)			0.8(4)			
0.10μF( <b>104</b> )				1.0(4)			0.8(4)			
0.15μF( <b>154</b> )							0.8(4)			

The part numbering code is shown in each ( ). The (4) code in T(mm) means number of elements (four).

Dimensions are shown in mm and Rated Voltage in Vdc.

# **Specifications and Test Methods**

			Ş	Specifications					
No.	Ite	em	Temperature Compensating Type	High Dielectric Type		Test Method			
1	Operating Temperatu	ıre Range	5C : −55°C to +125°C	R7 : −55°C to +125°C F5 : −30°C to +85°C					
2	Rated Vo	Itage	See the previous pages.		The rated voltage is defined as the maximum voltage which may be applied continuously to the capacitor. When AC voltage is superimposed on DC voltage, V <sup>p,p</sup> or V <sup>o,p</sup> , whichever is larger, should be maintained within the rated voltage range.				
3	Appearar	ice	No defects or abnormaliti	es	Visual inspection				
4	Dimensio	n	Within the specified dime	nsions	Using calipers				
5 Dielectric Strength No defects or abnormalities (5C) or 250% of the the terminations for charge current is le					No failure should be o (5C) or 250% of the rathe terminations for 1 charge current is less	ated voltage (R7, F5 to 5 seconds, provid	) is applie	ed between	
6	Insulation Resistance More than 10,000MΩ or 50 (Whichever is smaller)			500Ω • F	The insulation resistar age not exceeding the and within 2 minutes of	rated voltage at 25			
7	Capacita	nce	Within the specified tolera	ance	The capacitance/Q/D.		red at 25	℃ at the fre-	
			30pF min. : Q≧1000	Chan 25V main 4/V 40V	quency and voltage sh				
		ssipation Factor 30pF max. : Q≥400+20C		Char.     25V min.     16V     10V       R7     0.025 max.     0.035 max.     0.035 max.	Item Char. Frequency	5C 1±0.1MHz		/, F5 .1kHz	
	(D.F.)		C : Nominal Capacitance	F5 0.05 max. 0.07 max. —	Voltage	0.5 to 5Vr.m.s.		2Vr.m.s.	
			(pF)						
		Capacitance Change	Within the specified tolerance (Table A)	Char.         Temp. Range         Reference Temp. Temp.         Change           R7         −55 to +125℃         25℃         Within±15%           F5         −30 to +85℃         25℃         Within±22%	•	ature stage.	ned using		
		Temperature Coefficient	Within the specified tolerance (Table A)		When cycling the temperature sequentially from step1 through 5, the capacitance should be within the specified tolerance for the temperature coefficient and capacitance				
9	Capacitance Temperature				differences between	ift is calculated by d n the maximum and a and 5 by the capac	minimum	measured	
,	Characteristics				Step	Temperat	ure (℃)		
					1	25±			
		Capacitance Drift	Within ±0.2% or ±0.05 pF (Whichever is larger)		2	-55±3 (for 5C/ R7)		(for F5)	
		DIIII	(Willichever is larger)		3	25±		(EE)	
					5	125±3 (for 5C/R		(F5)	
						25±	.2		
					above 25℃ value o	nstant Type acitance change con over the temperature hin the specified rar	ranges s		
			No removal of the termina	ations or other defect should occur.	Solder the capacitor to	the test jig (glass e	poxy boa	ard) shown in	
10	Adhesive	Strength		b a	Fig. 1 using a eutectic with the test jig for 10- The soldering should I reflow method and sho soldering is uniform ar	solder. Then apply ±1 sec. be done either with a ould be conducted w	5N force an iron or vith care s	in parallel using the so that the	
10	of Termin	ation		<u> </u>	Type	a b	С	d	
					GNM1M GNM21	0.5 — 0.4 1.6	0.32	0.32	
				0.14	GNM31	0.8 2.5	0.25	0.8	
				Solder resist Copper foil		Fig. 1		(in mm)	

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### **Specifications and Test Methods**

Continued from the preceding page.

	1							
				Specifications				
No.	Ite	em	Temperature Compensating Type	High Dielectric Type	Test Method			
		Appearance	No defects or abnormaliti	es	Solder the capacitor to the test jig (glass epoxy board) in the			
		Capacitance	Within the specified tolera	ance	same manner and under the same conditions as (10).  The capacitor should be subjected to a simple harmonic motion			
11	Vibration Resistance	Q/D.F.	30pF min. : Q≥1000 30pF max. : Q≥400+20C C : Nominal Capacitance (pF)	Char.         25V min.         16V         10V           R7         0.025 max.         0.035 max.         0.035 max.           F5         0.05 max.         0.07 max.         -	having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 55Hz. The frequency range, from 10 to 55Hz and return to 10Hz, should be traversed in approximately 1 minute. This motion should be applied for a period of 2 hours in each of 3 mutually perpendicular directions (total of 6 hours).			
			No cracking or marking d	efects should occur.	Solder the capacitor on the test jig (glass epoxy board) shown			
12	2 Deflection		•GNM□□2  -GNM□□2  -GNM□2  -GNM□□2  -GNM□2  -GNM□2		in Fig. 2 using a eutectic solder. Then apply a force in the direction shown in Fig. 3 for 5±1 sec. The soldering should be done either with an iron or using the reflow method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock.  20 50 Pressurizing speed: 1.0mm/sec. Pressurize  Capacitance meter 45 45 (in mm)  Fig. 3			
				(in mm) Fig. 2	t=0.8mm (GNM21), 1.6mm (GNM31)			
13	Solderability of Termination		75% of the terminations are to be soldered evenly and continuously.		Immerse the capacitor in a solution of ethanol (JIS-K-8101) an rosin (JIS-K-5902) (25% rosin in weight proportion). Preheat at 80 to 120℃ for 10 to 30 seconds. After preheating, immerse in eutectic solder solution for 2±0.5 seconds at 230±5℃.			
			The measured and observed characteristics should satisfy the specifications in the following table.					
		Appearance	No marking defects		Preheat the capacitor at 120 to 150°C for 1 minute. Immerse the			
		Capacitance Change	Within ±2.5% or ±0.25pF (Whichever is larger)	R7 : Within ±7.5% F5 : Within ±20%	capacitor in a eutectic solder solution at 270±5°C for 10±0.5 seconds. Let sit at room temperature for 24±2 hours (temperature componenting type) or 48±4 hours (high disloctric constant			
14	Resistance to Soldering Heat	Q/D.F.	30pF min. : Q≥1000 30pF max. : Q≥400+20C C : Nominal Capacitance (pF)	Char.         25V min.         16V         10V           R7         0.025 max.         0.035 max.         0.035 max.           F5         0.05 max.         0.07 max.         -	ture compensating type) or 48±4 hours (high dielectric constant type), then measure.  • Initial measurement for high dielectric constant type Perform a heat treatment at 150±9° °C for one hour and then let sit for 48±4 hours at room temperature. Perform the initial			
		I.R.	More than 10,000MΩ or	500Ω • F (Whichever is smaller)	measurement.			
		Dielectric Strength	No failure					
			The measured and obser specifications in the follow	ved characteristics should satisfy the wing table.	Fix the capacitor to the supporting jig in the same manner and under the same conditions as (10). Perform the five cycles			
		Appearance	No marking defects		according to the four heat treatments listed in the following			
		Capacitance Change	Within ±2.5% or ±0.25pF (Whichever is larger)	R7 : Within ±7.5% F5 : Within ±20%	table. Let sit for 24±2 hours (temperature compensating type) or 48±4 hours (high dielectric constant type) at room temperature, then measure			
15	Temperature Cycle	Q/D.F.	30pF min. : Q≧1000 30pF max. : Q≥400+20C C : Nominal Capacitance (pF)	Char.         25V min.         16V         10V           R7         0.025 max.         0.035 max.         0.035 max.           F5         0.05 max.         0.07 max.         —	Step         1         2         3         4           Temp. (°C)         Min. Operating Temp. ±3         Room Temp. ±3         Room Temp. ±3         Room Temp. ±3         Temp. ±3         Temp. ±3         Temp. ±3         2 to 3           Time (min.)         30±3         2 to 3         30±3         2 to 3			
		I.R.		500Ω • F (Whichever is smaller)	• Initial measurement for high dielectric constant type  Perform a heat treatment at 150 = 90 °C for one hour and then			
		Dielectric Strength	No failure	, see to the second	let sit for 48±4 hours at room temperature. Perform the initial measurement.			
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## **Specifications and Test Methods**

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				Specifications			
No.	lt€	em	Temperature Compensating Type	High Dielectric Type	Test Method		
		The measured and observed characteristics should satis specifications in the following table.					
		Appearance	No marking defects				
		Capacitance Change	Within ±5% or ±0.5pF (Whichever is larger)	R7 : Within ±12.5% F5 : Within ±30%	Let the capacitor sit at 40±2°C and 90 to 95% humidity for		
16	Humidity Steady State	Q/D.F.	30pF and over : Q≥350 10pF and over, 30pF and below :	Char.       25V min.       16V       10V         R7       0.025 max.       0.035 max.       0.035 max.         F5       0.05 max.       0.07 max.       —	500±12 hours.  Remove and let sit for 24±2 hours (temperature compensating type) or 48±4 hours (high dielectric constant type) at room temperature, then measure.		
		I.R.	More than 1,000MΩ or 5	$0\Omega$ • F (Whichever is smaller)			
		Dielectric Strength	No failure				
			The measured and observed characteristics should satisfy the specifications in the following table.				
		Appearance	No marking defects				
		Capacitance Change	Within ±7.5% or ±0.75pF (Whichever is larger)	R7 : Within ±12.5% F5 : Within ±30%	Apply the rated voltage at 40±2℃ and 90 to 95% humidity for		
17	Humidity Load	Q/D.F.	30pF and over : Q≥200 30pF and below : Q≥100+10C/3 C : Nominal Capacitance (pF)	Char.     25V min.     16V     10V       R7     0.025 max.     0.035 max.     0.035 max.       F5     0.05 max.     0.07 max.     -	500±12 hours. Remove and let sit for 24±2 hours (temperature compensating type) or 48±4 hours (high dielectric constant type) at room temperature, then measure. The charge/discharge current is less than 50mA.		
		I.R.	More than $500 M\Omega$ or $250$	2 • F (Whichever is smaller)			
		Dielectric Strength	No failure				
			The measured and observed characteristics should satisfy the specifications in the following table.				
		Appearance	No marking defects				
		Capacitance Change	Within ±3% or ±0.3pF (Whichever is larger)	R7 : Within ±12.5% F5 : Within ±30%	Apply 200% of the rated voltage for 1000±12 hours at the		
18	High Temperature Load	Q/D.F.	30pF and over : Q≥350 10pF and over, 30pF and below : Q≥275+5C/2 10pF and below : Q≥200+10C	Char.       25V min.       16V       10V         R7       0.025 max.       0.035 max.       0.035 max.         F5       0.05 max.       0.07 max.       -	maximum operating temperature ±3°C. Let sit for 24±2 hours (temperature compensating type) or 48±4 hours (high dielectric constant type) at room temperature, then measure. The charge/discharge current is less than 50mA.  •Initial measurement for high dielectric constant type. Apply 200% of the rated DC voltage for one hour at the maximum operating temperature ±3°C. Remove and let sit for 48±4		
			C : Nominal Capacitance (pF)		hours at room temperature. Perform initial measurement.		
		I.R.	More than 1,000MΩ or 5	0Ω • F (Whichever is smaller)			
		Dielectric Strength	No failure				

#### Table A

		Capacitance Change from 25℃ (%)					
Char.	Nominal Values (ppm/°C) Note 1	-55		-30		-10	
	(ppin/c) Note i	Max.	Min.	Max.	Min.	Max.	Min.
5C	0±30	0.58	-0.24	0.40	-0.17	0.25	-0.11

Note 1 : Nominal values denote the temperature coefficient within a range of 25°C to 125°C.